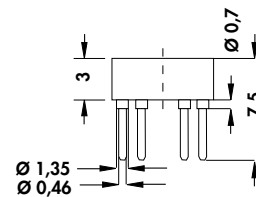
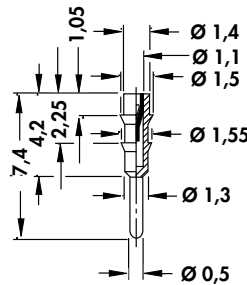
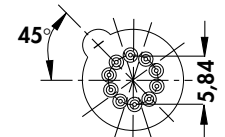
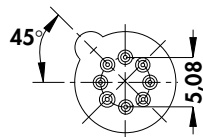
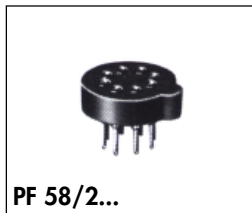
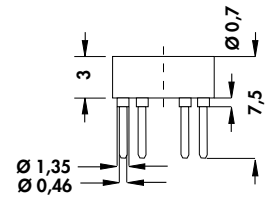
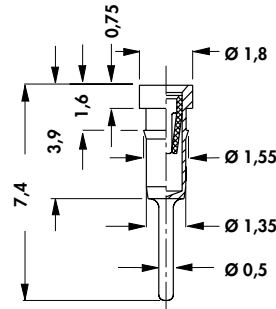
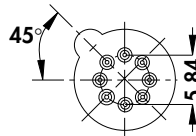
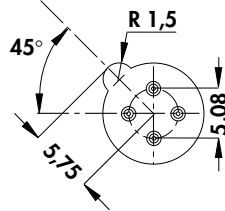
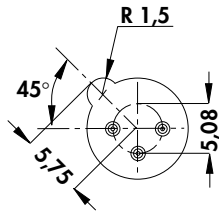
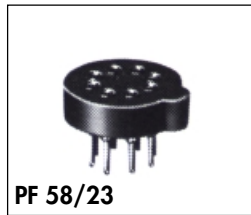


Fassungen für TO 5

Sockets for TO 5

Supports pour TO 5



...bitte Oberfläche der Kontakthülse angeben:
G = vergoldet
Z = verzinkt

...please indicate contact shell surface:
G = gold
Z = tinned

...veuillez indiquer revêtement du corps du contact:
G = doré
Z = étamé

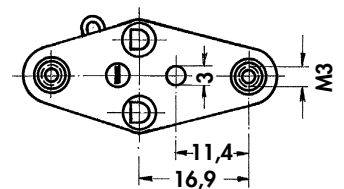
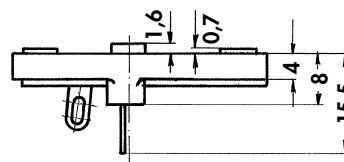
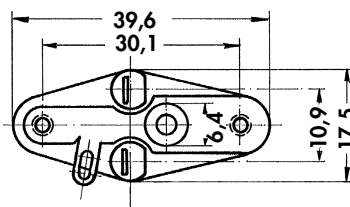
Fassungen für Leistungstransistoren

Sockets for Power Transistors

Supports pour transistors de puissance



TF 3/2
(TO 3)



Material/Technische Daten

Isolierkörper: glasfaserverstärktes Polyamid
Kontakt: Federbronze 2 μm Ni,
0,5 μm Au

Kontaktbelastbarkeit: 5 A max.
Kapazität: 1 pF
Kontaktwiderstand: 10 m Ω
Isolationswiderstand: 10^{14} Ω
Temperaturbereich: -55°C...+160°C

Material/Technical Data:

Insulator: Polyamide glassfibre filled
Contact: Special bronze 2 μm Ni,
0,5 μm Au

Current rating: 5 A max.
Capacitance: 1 pF
Contact resistance: 10 m Ω
Insulation resistance: 10^{14} Ω
Temperature range: -55°C...+160°C

Matière/Caractéristiques techniques:

Isolant: Polyamide renforcé de fibre de verre
Contact: Bronze spécial 2 mm Ni,
0,5 mm Au

Charge par contact: 5 A max.
Capacité: 1 pF
Résistance de contact: 10 m Ω
Résistance d'isolation: 10^{14} Ω
Gamme de températures: -55°C...+160°C